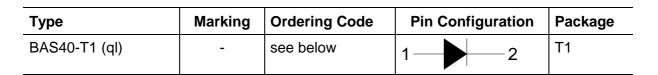


HiRel Silicon Schottky Diode

- HiRel Discrete and Microwave Semiconductor
- General-purpose diodes for high-speed switching
- Circuit protection
- Voltage clamping
- High-level detecting and mixing
- Hermetically sealed microwave package
- Cesa Space Qualification Expected 1998

ESA/SCC Detail Spec. No.: 5512/020 Type Variant No. 03 (tbc.)

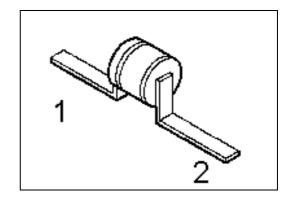
ESD: Electrostatic discharge sensitive device, observe handling precautions!



(ql) Quality Level: P: Professional Quality, Ordering Code: Q62702A1176

H: High Rel Quality,S: Space Quality,Ordering Code: on requeston request

(see order instructions for ordering example)





Maximum Ratings

Parameter	Symbol	Values	Unit
Reverse Voltage	V_R	40	V
Forward Current	I _F	120	mA
Surge Forward Current 1)	I _{FSM}	170	mA
Power Dissipation 2)	P _{tot}	250	mW
Operating Temperature Range	T _{op}	-55 to +150	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C
Soldering Temperature 3)	T _{sol}	+250	°C
Junction Temperature	T _j	150	°C
Thermal Resistance Junction-Case	R _{th(j-c)}	100	K/W

Electrical Characteristics

at T_A=25°C; unless otherwise specified

Parameter	Symbol		Values		
		min.	typ.	max.	
DC Characteristics	·		·		
Reverse Current 1	I _{R1}	-	-	10	μΑ
V _R =40V					
Reverse Current 2	I _{R2}	-	-	1	μΑ
$V_R=30V$					
Forward Voltage 1	V_{F1}	0,29	0,33	0,39	V
I _{F1} =1mA					
Forward Voltage 2	V_{F2}	0,42	0,45	0,54	V
I _{F2} =10mA					
Forward Voltage 3	V _{F3}	0,68	0,7	0,85	V
I _{F3} =40mA					
Differential Forward Resistance 4)	R _{FD}	7,5	10	11,5	Ω
I=10mA, I=15mA					
AC Characteristics	<u> </u>			•	
Total Capacitance	Ст	2,2	2,9	5,0	pF
$V_R=0V$; $f=1MHz$					

- 1.) $t \le 10$ ms, Duty Cycle=10%
- 2.) At T_{CASE} = 125 °C. For T_{CASE} > 125 °C derating is required.
 3.) During 5 sec. maximum. The same terminal shall not be resoldered until 3 minutes have elapsed.



Order Instructions:

Full type variant including package variant and quality level must be specified by the orderer. For *HiRel* Discrete and Microwave Semiconductors the ordering code specifies device family and quality level only.

Ordering Form:

Ordering Code: Q.....

BAS40- (x) (ql)

(x): Package Variant (ql): Quality Level

Ordering Example:

Ordering Code: Q62702A1176

BAS40-T1 P

For BAS40 in T1 Package; Professional Quality Level

Further Informations:

See our WWW-Pages:

- Discrete and RF-Semiconductors (Small Signal Semiconductors) www.infineon.com/products/discrete/ hirel.htm
- HiRel Discrete and Microwave Semiconductors www.infineon.com/products/discrete/hirel.htm

Please contact also our marketing division:

Tel.: ++89 234 24480 Fax.: ++89 234 28438

e-mail: martin.wimmers@infineon.com

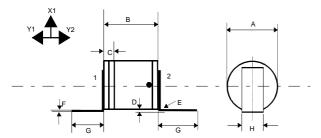
Address: Infineon Technologies Semiconductors,

High Frequency Products Marketing,

P.O.Box 801709, D-81617 Munich



T1 Package



Symbol	Millimetre			
	min	max		
Α	1,30	1,45		
В	1,15	1,35		
С	-	0,40		
D	0,10	0,50		
E	ı	0,30		
F	0,06	0,10		
G	5,50	-		
Н	0,40	0,60		

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Infineon Technologies Semiconductors is a certified CECC and QS9000 manufacturer (this includes ISO 9000).